

Light is OSRAM

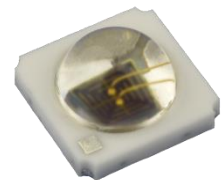
OSRAM
Opto Semiconductors

Our Brand
LED ENGIN

LuxiGen™ LZ1 Emitter Series

1050nm LED Emitter

LZ1-00R802



Key Features

- 1050nm Infrared LED
- Ultra-small foot print – 4.4mm x 4.4mm
- Surface mount ceramic package with integrated glass lens
- Very low Thermal Resistance (6.0°C/W)
- Very high Radiant Flux density
- JEDEC Level 1 for Moisture Sensitivity Level
- Lead (Pb) free and RoHS compliant
- Reflow solderable
- Emitter available on Standard or Miniature MCPCB (optional)

Typical Applications

- Machine vision
- Solar panel testing
- Sensing
- Life science

Note

This product emits non-visible infrared light, which can be hazardous depending on total system configuration (including, but not limited to optics, drive current and temperature). Observe safety precaution given in IEC 62471 when operating this product.

LZ1-00R802

Part number options

Base part number

| Part number | Description |
|-------------|--|
| LZ1-00R802 | LZ1 Infrared 1050nm Emitter |
| LZ1-10R802 | LZ1 Infrared 1050nm Emitter on Standard Star MCPCB |

Bin kit option codes

| Kit number suffix | Min flux Bin | Wavelength Bin Range | Description |
|----------------------|-----------------|-------------------------|--|
| 0000 | KL | F11 | full distribution flux; full distribution wavelength |

LZ1-00R802

Flux Bins

Table 1:

| Bin Code (mW) | Minimum Flux @ I_F = 1000mA^[1] | Maximum Flux @ I_F = 1000mA^[1] (mW) |
|-------------------------|--|--|
| KL | 640 | 1000 |

Note for Table 1:

1. Flux performance is measured at 10ms pulse, T_C = 25°C. LED Engin maintains a tolerance of ±10% on flux measurements.

Wavelength Bins

Table 2:

| Bin Code | Minimum Peak Wavelength (λ_p) @ I_F = 1000mA^[1] (nm) | Maximum Peak Wavelength (λ_p) @ I_F = 1000mA^[1] (nm) |
|-----------------|---|---|
| F11 | 1000 | 1100 |

Note for Table 2:

1. Wavelength is measured at 10ms pulse, T_C = 25°C. LED Engin maintains a tolerance of ± 2.0nm on peak wavelength measurements.

Forward Voltage Bin

Table 3:

| Bin Code | Minimum Forward Voltage (V_F) @ I_F = 1000mA^[1] (V) | Maximum Forward Voltage (V_F) @ I_F = 1000mA^[1] (V) |
|-----------------|--|--|
| 0 | 1.2 | 2.2 |

Note for Table 3:

1. Forward voltage is measured at 10ms pulse, T_C = 25°C. LED Engin maintains a tolerance of ± 0.04V for forward voltage measurements.

Absolute Maximum Ratings

Table 4:

| Parameter | Symbol | Value | Unit |
|--|-----------|------------|------|
| DC Forward Current ^[1] | I_F | 1000 | mA |
| Peak Pulsed Forward Current ^[2] | I_{FP} | 1000 | mA |
| Reverse Voltage | V_R | See Note 3 | V |
| Storage Temperature | T_{stg} | -40 ~ +85 | °C |
| Junction Temperature | T_J | 115 | °C |
| Soldering Temperature ^[4] | T_{sol} | 260 | °C |
| Allowable Reflow Cycles | | 3 | |
| ESD Sensitive Device | | | |
| Class 0 ANSI/ ESDA/ JEDEC | | | |
| JS-001 HBM | | | |
| ESD Sensitivity ^[5] | | | |

Notes for Table 4:

- Maximum DC forward current is determined by thermal resistance and case temperature. Follow Figure 11 for current derating.
- Pulse forward current conditions: Pulse Width \leq 10msec and Duty Cycle \leq 10%.
- LEDs are not designed to be reverse biased.
- Solder conditions per JEDEC 020D. See Reflow Soldering Profile Figure 3.
- LED Engin recommends taking reasonable precautions towards possible ESD damages and handling the emitter in an electrostatic protected area (EPA). An EPA may be adequately protected by ESD controls as outlined in ANSI/ESD S6.1.

Optical Characteristics @ $T_c = 25^\circ\text{C}$

Table 5:

| Parameter | Symbol | Typical | Unit |
|--|-------------------------|---------|---------|
| Radiant Flux (@ $I_F = 1000\text{mA}$) ^[1] | Φ_V | 750 | mW |
| Peak Wavelength (@ $I_F = 1000\text{mA}$) | λ_D | 1050 | nm |
| Viewing Angle ^[2] | $2\Theta_{\frac{1}{2}}$ | 90 | Degrees |
| Total Included Angle ^[3] | $\Theta_{0.9}$ | 110 | Degrees |

Notes for Table 5:

- This product emits non visible infrared light, which can be hazardous depending on total system configuration (including, but not limited to optics, drive current and temperature). Observe safety precaution given in IEC 62471 when operating this product.
- Viewing Angle is the off axis angle from emitter centerline where the radiant intensity is $\frac{1}{2}$ of the peak value.
- Total Included Angle is the total angle that includes 90% of the total radiant flux.

Electrical Characteristics @T_c = 25°C

Table 6:

| Parameter | Symbol | Typical | Unit |
|--|----------------------------------|---------|-------|
| Forward Voltage (@ I _F = 1000mA) | V _F | 1.6 | V |
| Temperature Coefficient of Forward Voltage | ΔV _F /ΔT _J | -2.4 | mV/°C |
| Thermal Resistance, electrical (Junction to Case) | RΘ _{J-C, el} | 6.0 | °C/W |

IPC/JEDEC Moisture Sensitivity Level

Table 7 - IPC/JEDEC J-STD-20D.1 MSL Classification:

| Level | Soak Requirements | | | | | |
|-------|-------------------|-------------------|--------------|-----------------|-------------|------------|
| | Floor Life | | Standard | | Accelerated | |
| | Time | Conditions | Time (hrs) | Conditions | Time (hrs) | Conditions |
| 1 | Unlimited | ≤ 30°C/ 85% RH | 168 +5/-0 | 85°C/ 85% RH | n/a | n/a |

Notes for Table 7:

- The standard soak time includes a default value of 24 hours for semiconductor manufacturer's exposure time (MET) between bake and bag and includes the maximum time allowed out of the bag at the distributor's facility.

LZ1-00R802

Mechanical Dimensions (mm)

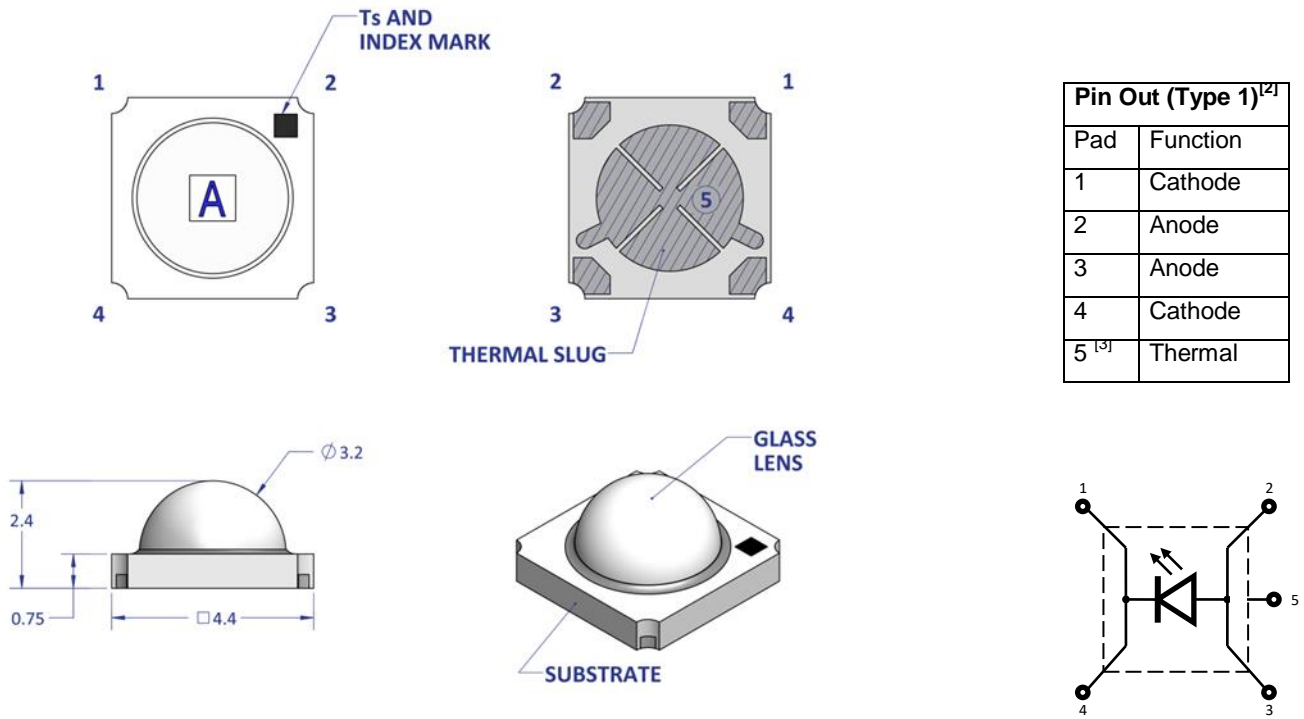


Figure 1: Package Outline Drawing

Notes for Figure 1:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.
2. This emitter pin-out is reversed to that of LZ1-00B202, LZ1-00G102, LZ1-00A102 and LZ1-00xW02.
3. Thermal contact, Pad 5, is electrically neutral.
4. T_c (case temperature) point is Pad 5. Because it's not easily accessible, the recommended temperature measurement point is side of the substrate.

Recommended Solder Pad Layout (mm)

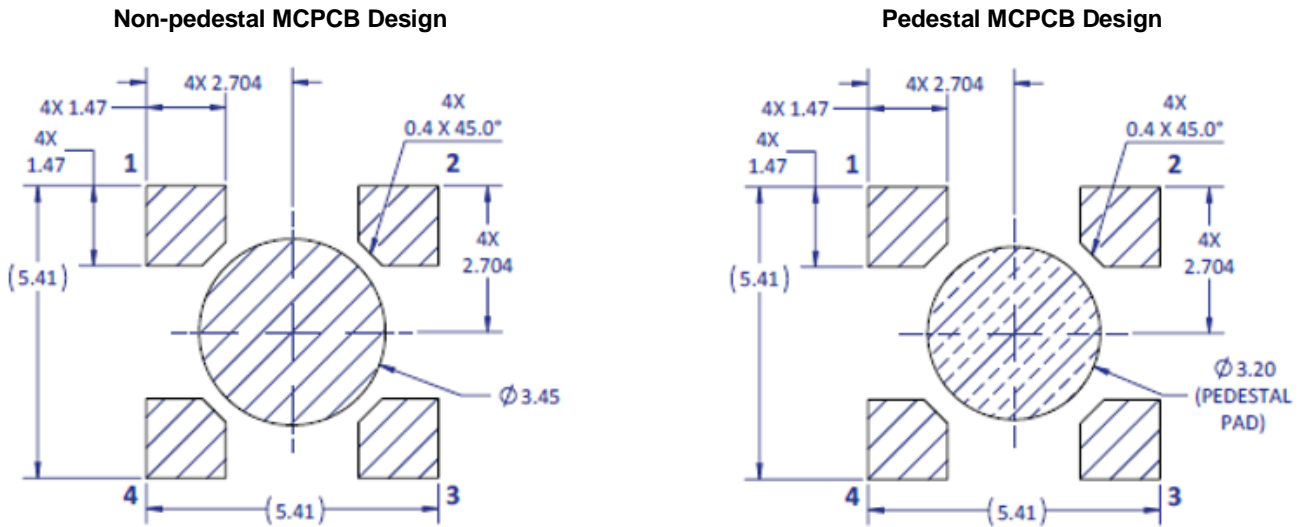


Figure 2a: Recommended solder pad layout for anode, cathode, and thermal pad for pedestal design

Notes for Figure 2a:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.
2. Pedestal MCPCB allows the emitter thermal slug to be soldered directly to the metal core of the MCPCB. Such MCPCB eliminate the high thermal resistance dielectric layer that standard MCPCB technologies use in between the emitter thermal slug and the metal core of the MCPCB, thus lowering the overall system thermal resistance.
3. LED Engin recommends x-ray sample monitoring for solder voids underneath the emitter thermal slug. The total area covered by solder voids should be less than 20% of the total emitter thermal slug area. Excessive solder voids will increase the emitter to MCPCB thermal resistance and may lead to higher failure rates due to thermal over stress.

Recommended Solder Mask Layout (mm)

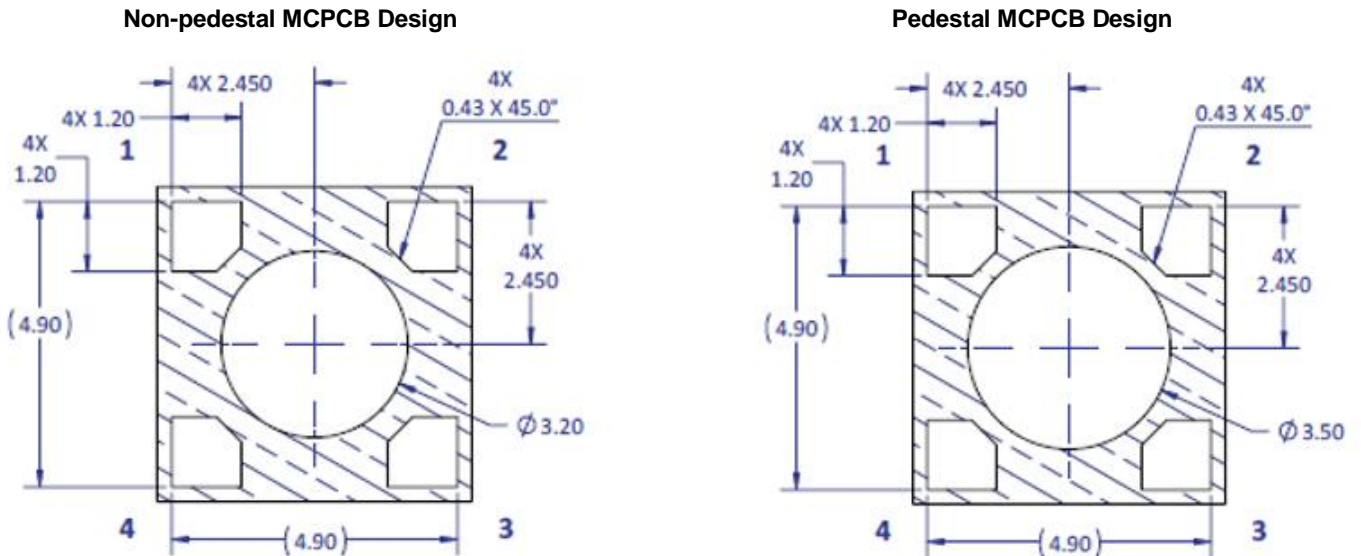


Figure 2b: Recommended solder mask opening for anode, cathode, and thermal pad for pedestal design

Note for Figure 2b:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.

Recommended 8 mil Stencil Apertures Layout (mm)

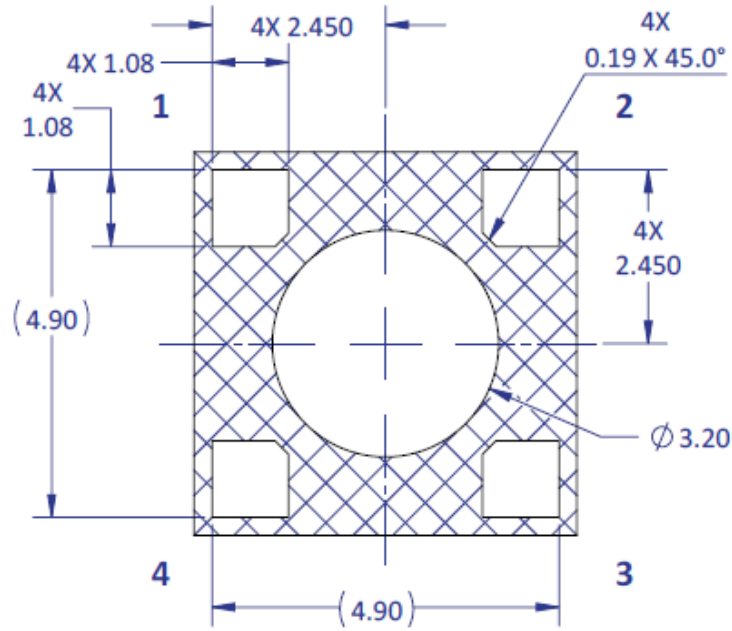


Figure 2c: Recommended 8mil stencil apertures layout for anode, cathode, and thermal pad for pedestal design

Note for Figure 2c:

- 1. Unless otherwise noted, the tolerance = ± 0.20 mm.

Reflow Soldering Profile

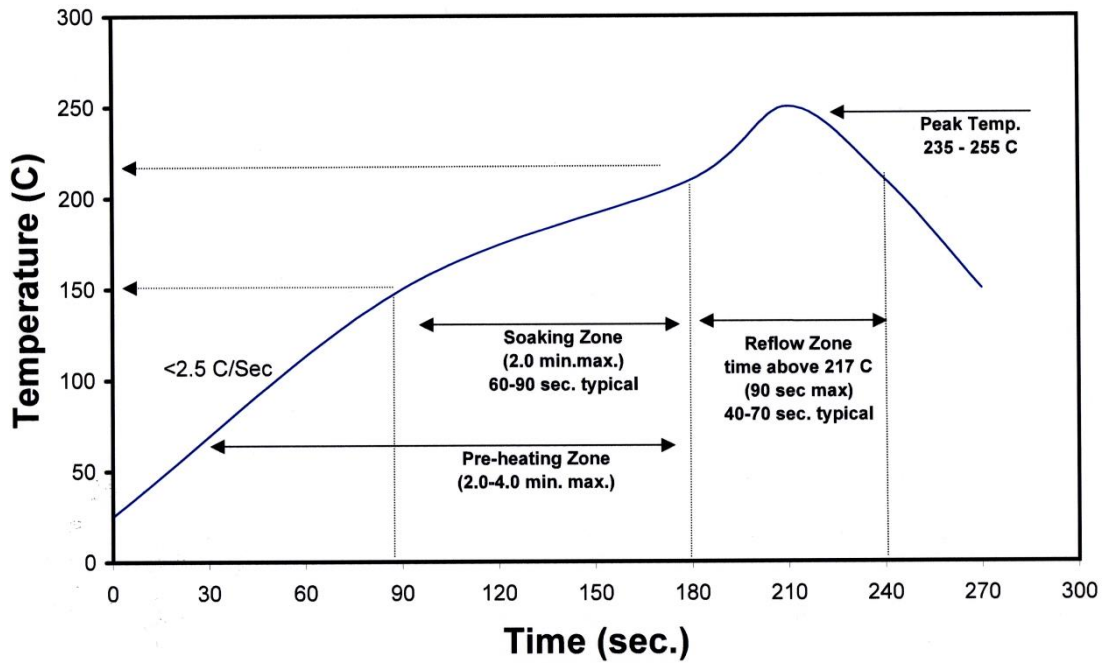


Figure 3: Reflow soldering profile for lead free soldering

Typical Radiation Pattern

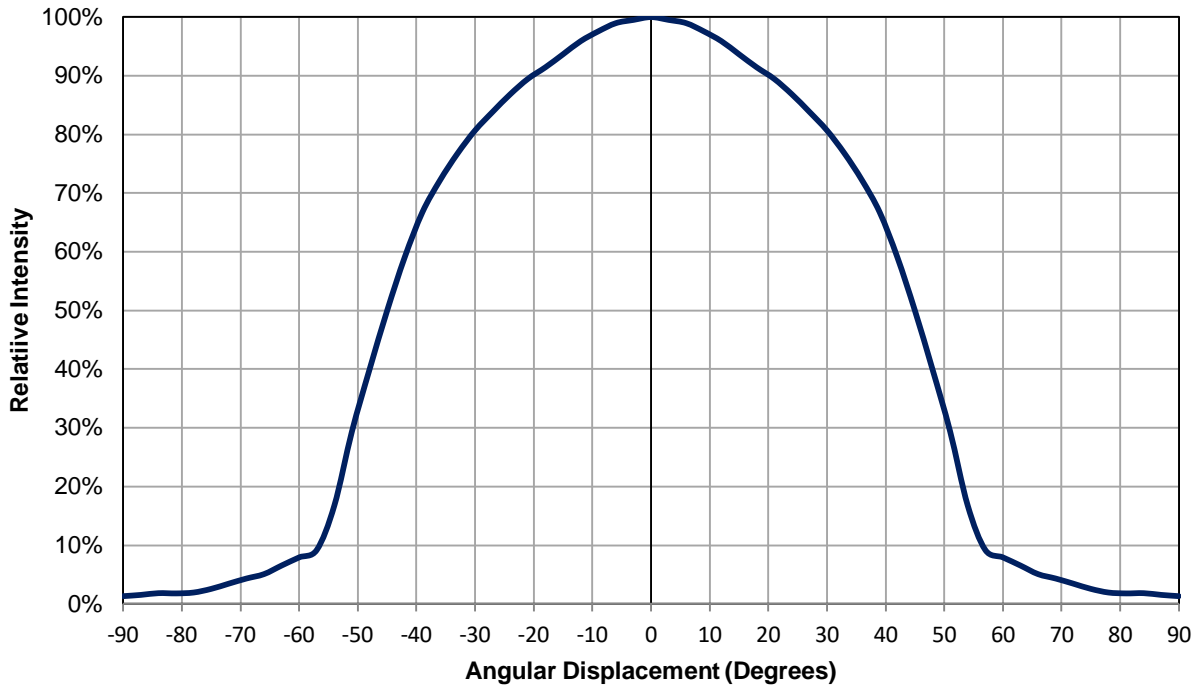


Figure 4: Typical representative spatial radiation pattern

Typical Relative Spectral Power Distribution

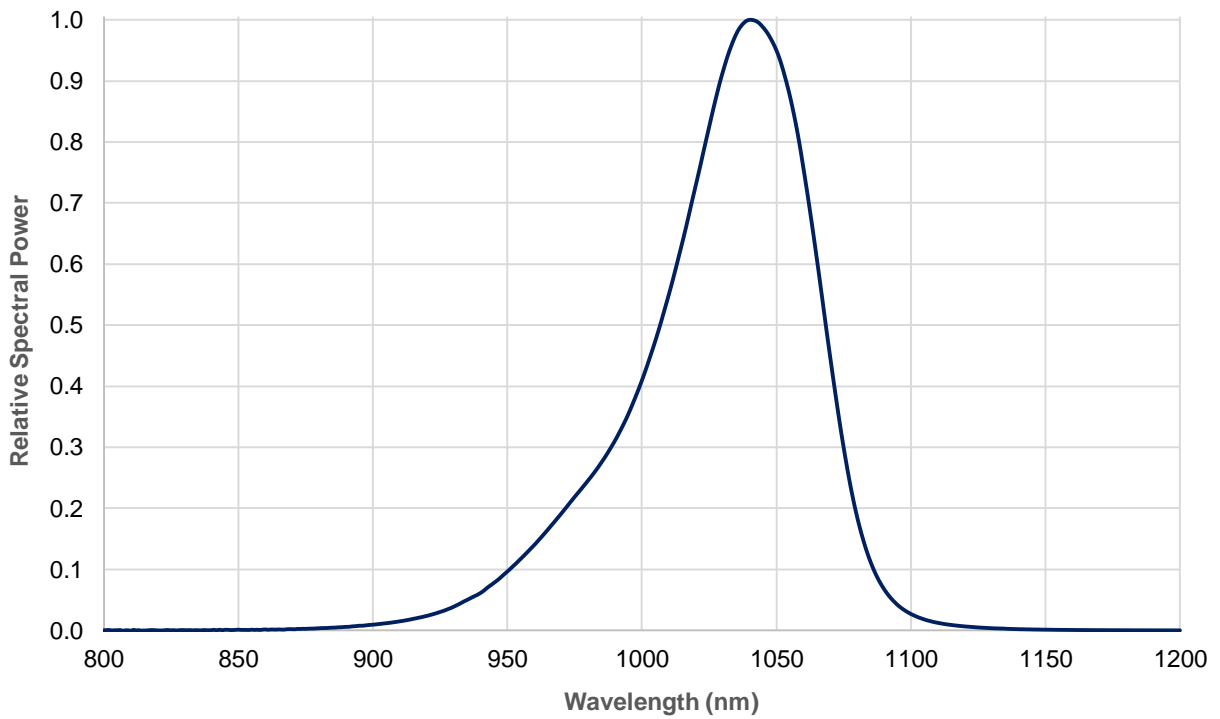


Figure 5: Typical relative spectral power vs. wavelength @ T_C = 25°C, 1000mA

Typical Forward Current Characteristics

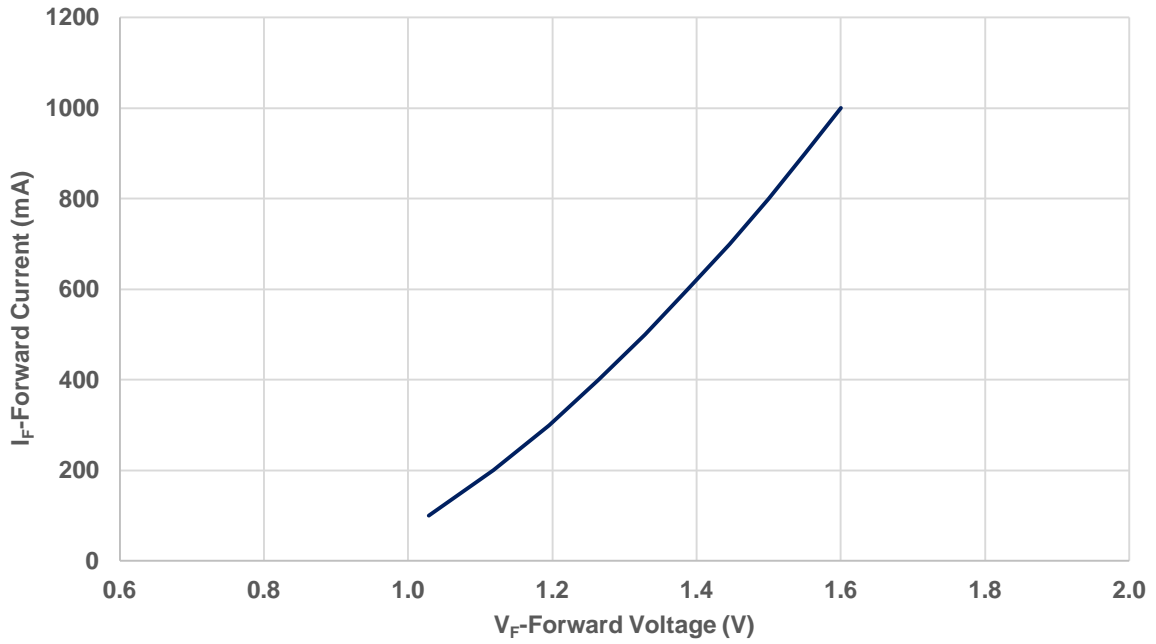


Figure 6: Typical forward current vs. forward voltage @ T_C = 25°C

Typical Normalized Relative Flux over Current

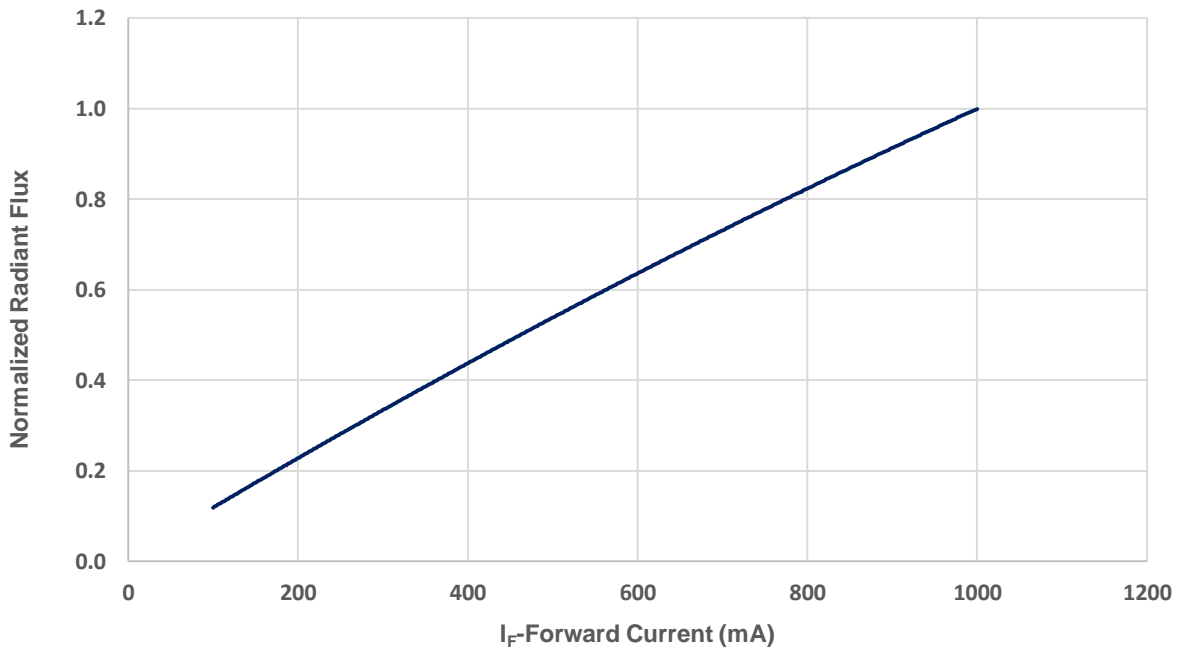


Figure 7: Typical relative luminous flux vs. forward current @ T_C = 25°C

Typical Normalized Relative Flux over Temperature

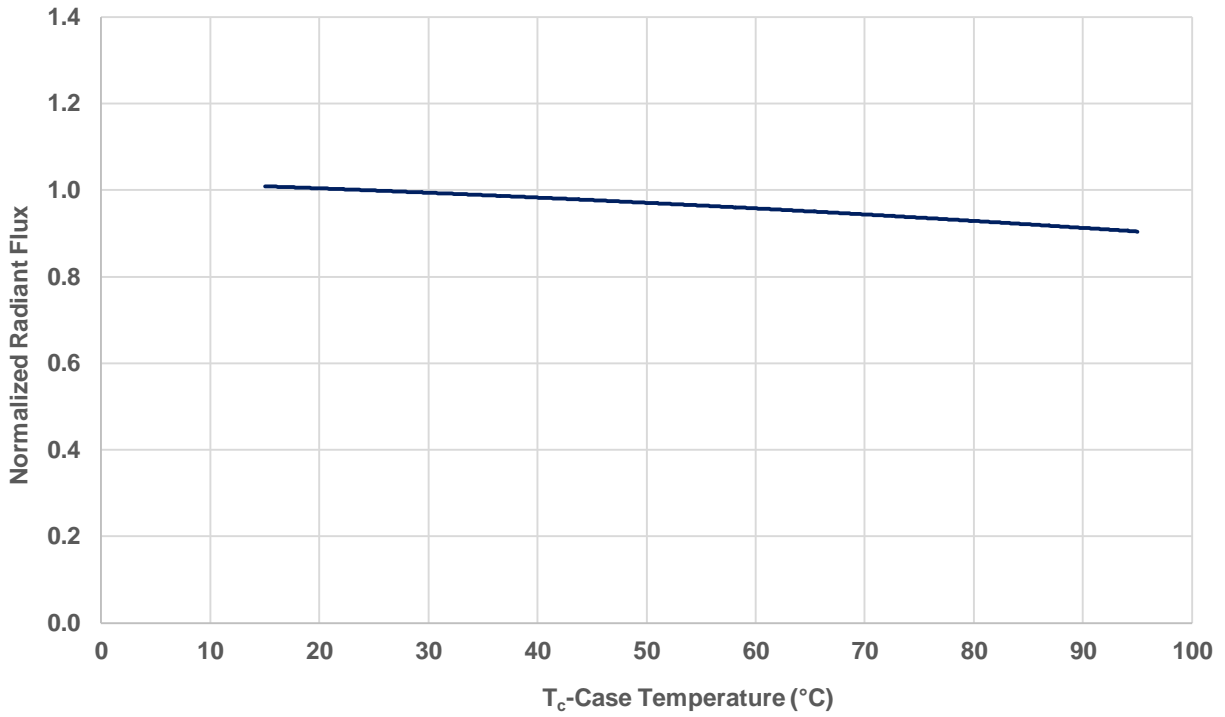


Figure 8: Typical relative luminous flux vs. case temperature @1000mA

Typical Peak Wavelength Shift over Current

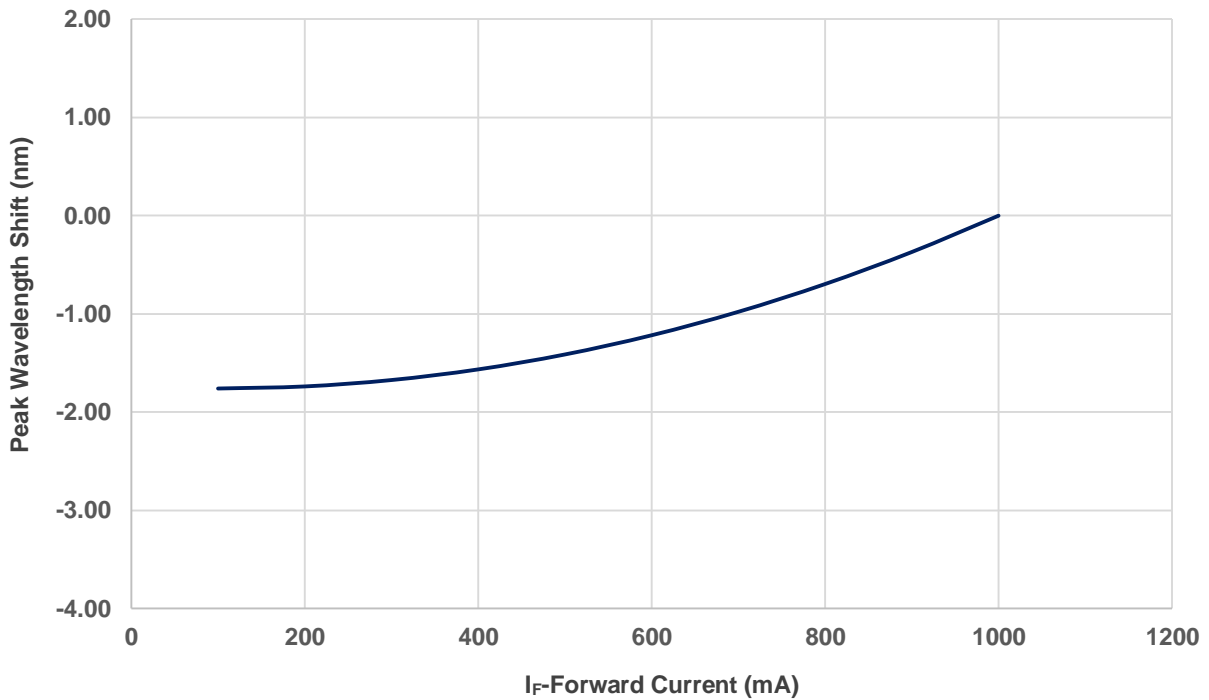


Figure 9: Typical peak wavelength shift vs. forward current @ T_C = 25°C

Typical Peak Wavelength Shift over Temperature

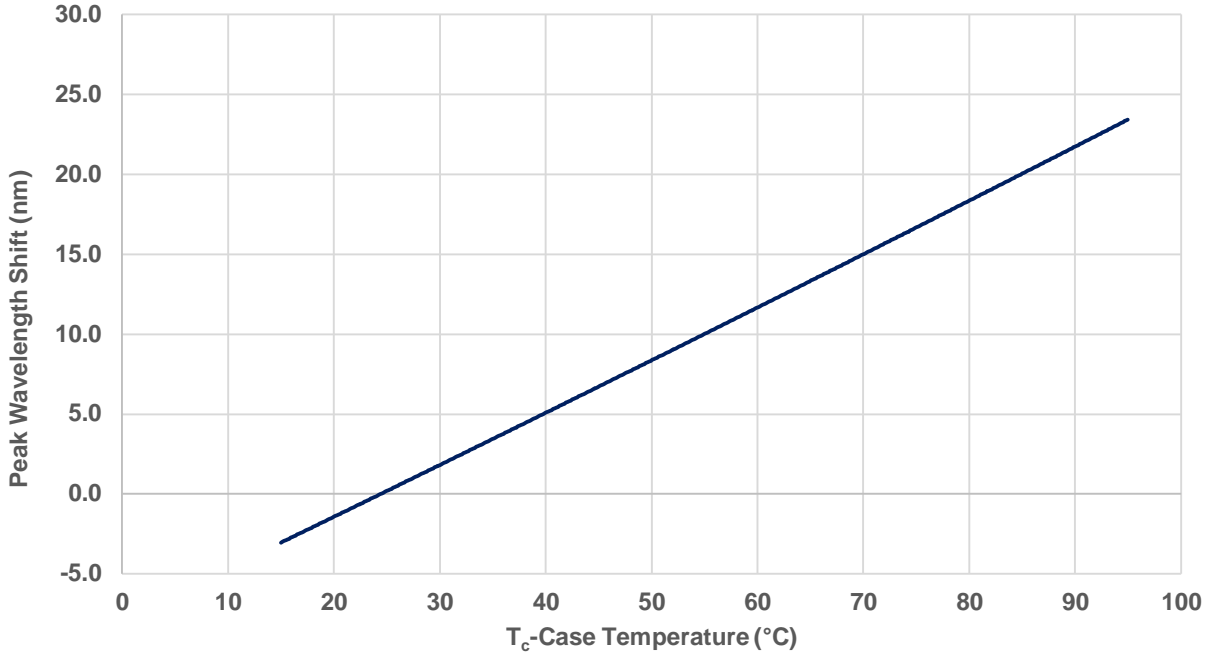


Figure 10: Typical peak wavelength shift vs. case temperature @ 1000mA

Current De-rating

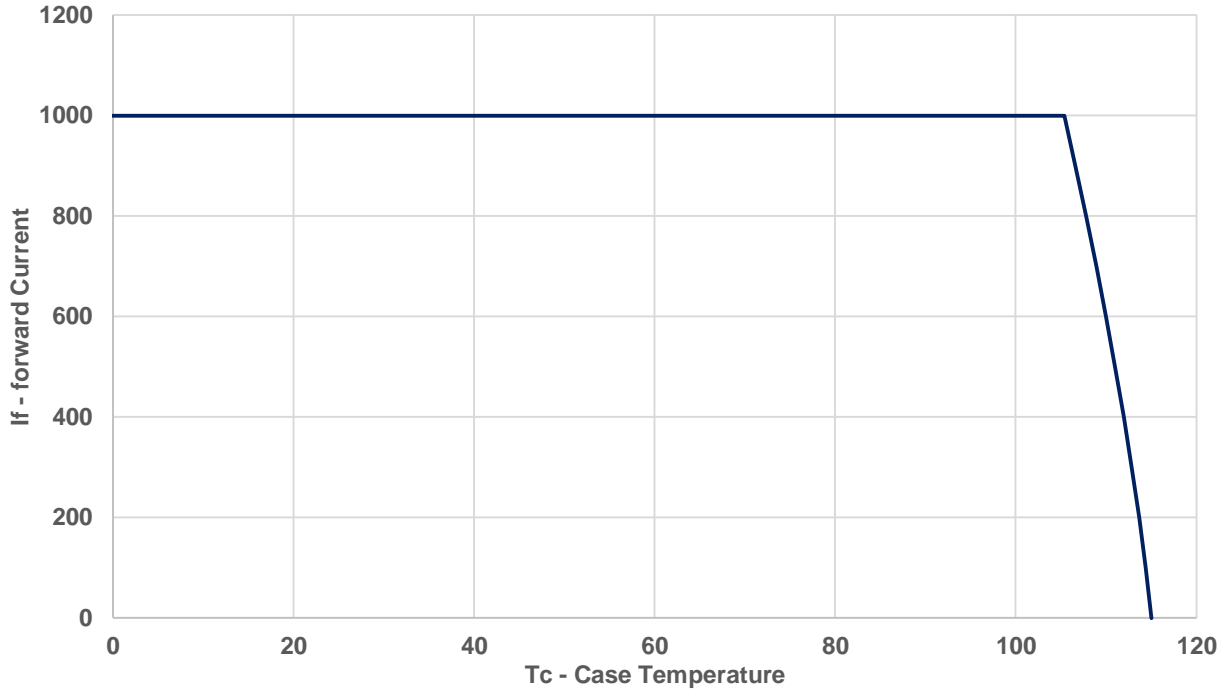


Figure 11: Maximum forward current vs. case temperature based on T_{J(MAX)} = 115°C

Notes for Figure 11:

- 1. R_{Θ_{J-C}} [Junction to Case Thermal Resistance] for LZ1-00R802 is 6.0°C/W.
- 2. R_{Θ_{J-A}} [Junction to Ambient Thermal Resistance] = R_{Θ_{J-C}} + R_{Θ_{C-A}} [Case to Ambient Thermal Resistance].

Emitter Tape and Reel Specifications (mm)

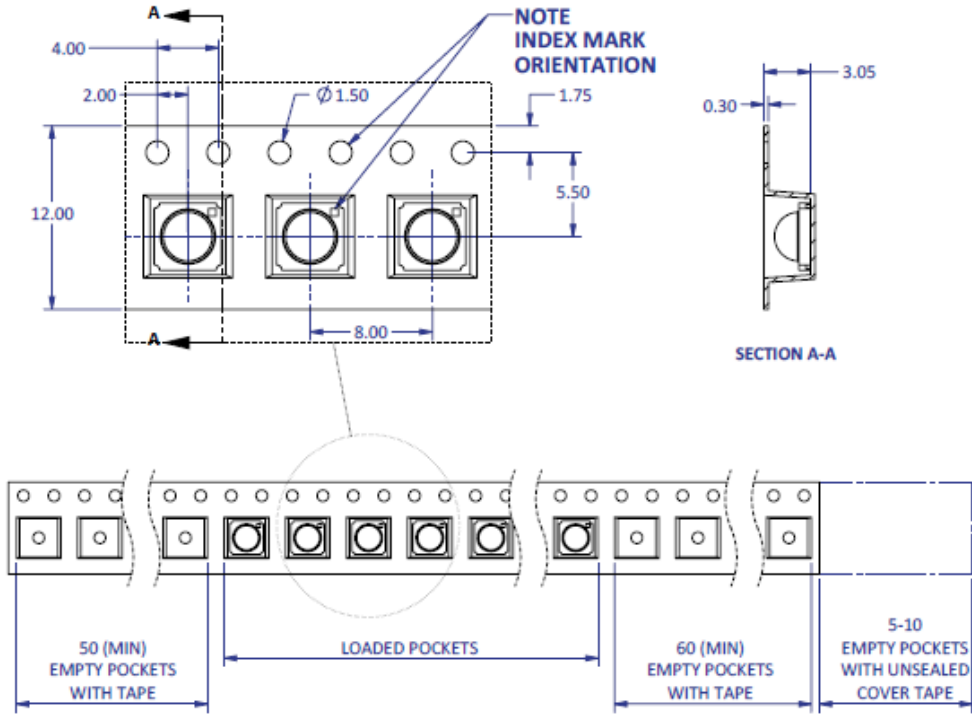


Figure 12: Emitter carrier tape specifications (mm).

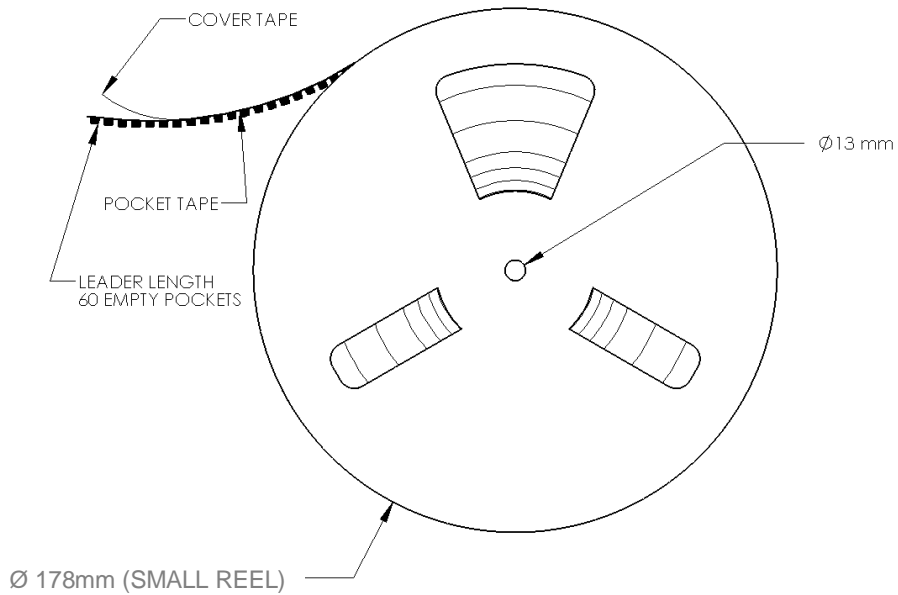


Figure 13: Emitter reel specifications (mm).

Notes for Figure 13:

1. Small reel quantity: 500 emitters
2. Single flux bin and single wavelength bin per reel.

Additional Notes for Figures 12 and 13:

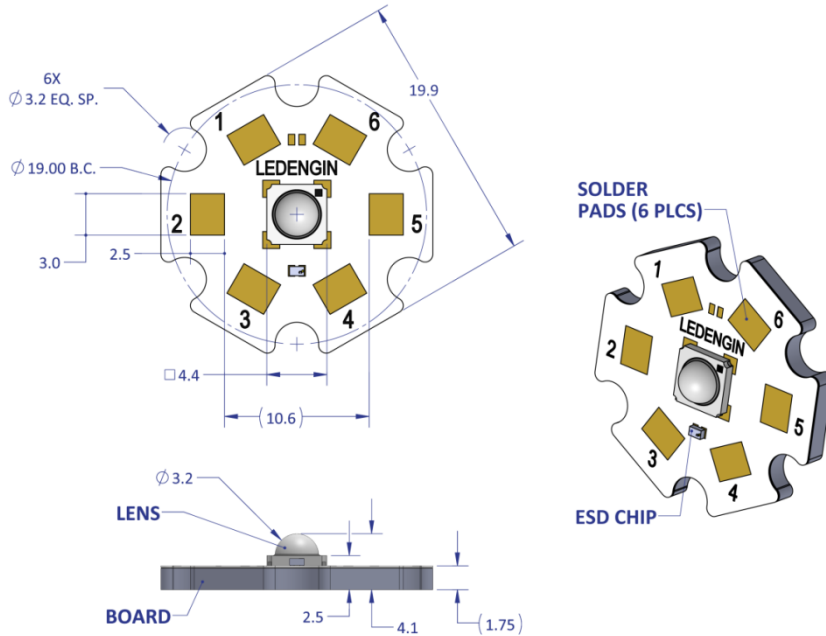
Tapes and reels are sipped in airtight bags in order to reduce the onset of silver tarnish. We recommend bags only be opened when ready to use emitters. Partially used reels or trays should be stored in airtight bags or in storage purged with nitrogen.

LZ1 MCPCB Family

| Part number | Type of MCPCB | Diameter (mm) | Emitter + MCPCB Thermal Resistance (°C/W) | Typical Vf (V) | Typical If (mA) |
|-------------|----------------|---------------|---|----------------|-----------------|
| LZ1-1xxxxx | 1-channel Star | 19.9 | 6.0 + 1.5 = 7.5 | 1.6 | 1000 |

LZ1-1xxxxx

1 channel, Standard Star MCPCB (1x1) Dimensions (mm)



Notes:

1. Unless otherwise noted, the tolerance = ± 0.2 mm.
2. Slots in MCPCB are for M3 or #4-40 mounting screws.
3. LED Engin recommends plastic washers to electrically insulate screws from solder pads and electrical traces.
4. LED Engin recommends using thermal interface material when attaching the MCPCB to a heat sink.
5. The thermal resistance of the MCPCB is: RΘC-B 1.5°

Components used

- MCPCB: HT04503 (Bergquist)
- ESD/TVS Diode: BZT52C5V1LP-7 (Diodes, Inc., for 1 LED die)
- VBUS05L1-DD1 (Vishay Semiconductors, for 1 LED die)

| Pad layout | | | |
|------------|-----------|------------|-----------|
| Ch. | MCPCB Pad | String/die | Function |
| 1 | 1,2,3 | 1/A | Cathode - |
| | 4,5,6 | | Anode + |

Application Guidelines

MCPCB Assembly Recommendations

A good thermal design requires an efficient heat transfer from the MCPCB to the heat sink. In order to minimize air gaps in between the MCPCB and the heat sink, it is common practice to use thermal interface materials such as thermal pastes, thermal pads, phase change materials and thermal epoxies. Each material has its pros and cons depending on the design. Thermal interface materials are most efficient when the mating surfaces of the MCPCB and the heat sink are flat and smooth. Rough and uneven surfaces may cause gaps with higher thermal resistances, increasing the overall thermal resistance of this interface. It is critical that the thermal resistance of the interface is low, allowing for an efficient heat transfer to the heat sink and keeping MCPCB temperatures low. When optimizing the thermal performance, attention must also be paid to the amount of stress that is applied on the MCPCB. Too much stress can cause the ceramic emitter to crack. To relax some of the stress, it is advisable to use plastic washers between the screw head and the MCPCB and to follow the torque range listed below. For applications where the heat sink temperature can be above 50°C, it is recommended to use high temperature and rigid plastic washers, such as polycarbonate or glass-filled nylon.

LED Engin recommends the use of the following thermal interface materials:

- Bergquist's Gap Pad 5000S35, 0.020in thick
 - Part Number: Gap Pad® 5000S35 0.020in/0.508mm
 - Thickness: 0.020in/0.508mm
 - Thermal conductivity: 5 W/m-K
 - Continuous use max temperature: 200°C
 - Using M3 Screw (or #4 screw), with polycarbonate or glass-filled nylon washer (#4) the recommended torque range is: 20 to 25 oz-in (1.25 to 1.56 lbf-in or 0.14 to 0.18 N-m)

- 3M's Acrylic Interface Pad 5590H
 - Part number: 5590H @ 0.5mm
 - Thickness: 0.020in/0.508mm
 - Thermal conductivity: 3 W/m-K
 - Continuous use max temperature: 100°C
 - Using M3 Screw (or #4 screw), with polycarbonate or glass-filled nylon washer (#4) the recommended torque range is: 20 to 25 oz-in (1.25 to 1.56 lbf-in or 0.14 to 0.18 N-m)

Mechanical Mounting Considerations

The mounting of MCPCB assembly is a critical process step. Excessive mechanical stress build up in the MCPCB can cause the MCPCB to warp which can lead to emitter substrate cracking and subsequent cracking of the LED dies

LED Engin recommends the following steps to avoid mechanical stress build up in the MCPCB:

- Inspect MCPCB and heat sink for flatness and smoothness.
- Select appropriate torque for mounting screws. Screw torque depends on the MCPCB mounting method (thermal interface materials, screws, and washer).
- Always use three M3 or #4-40 screws with #4 washers.
- When fastening the three screws, it is recommended to tighten the screws in multiple small steps. This method avoids building stress by tilting the MCPCB when one screw is tightened in a single step.
- Always use plastic washers in combinations with the three screws. This avoids high point contact stress on the screw head to MCPCB interface, in case the screw is not seated perpendicular.
- In designs with non-tapped holes using self-tapping screws, it is common practice to follow a method of three turns tapping a hole clockwise, followed by half a turn anti-clockwise, until the appropriate torque is reached.

Wire Soldering

- To ease soldering wire to MCPCB process, it is advised to preheat the MCPCB on a hot plate of 125-150°C. Subsequently, apply the solder and additional heat from the solder iron will initiate a good solder reflow. It is recommended to use a solder iron of more than 60W.
- It is advised to use lead-free, no-clean solder. For example: SN-96.5 AG-3.0 CU 0.5 #58/275 from Kester (pn: 24-7068-7601)

LZ1-00R802

About LED Engin

LED Engin, an OSRAM brand based in California's Silicon Valley, develops, manufactures, and sells advanced LED emitters, optics and light engines to create uncompromised lighting experiences for a wide range of entertainment, architectural, general lighting and specialty applications. LuxiGen™ multi-die emitter and secondary lens combinations reliably deliver industry-leading flux density, upwards of 5000 quality lumens to a target, in a wide spectrum of colors including whites, tunable whites, multi-color and UV LEDs in a unique patented compact ceramic package. Our LuxiTune™ series of tunable white lighting modules leverage our LuxiGen emitters and lenses to deliver quality, control, freedom and high density tunable white light solutions for a broad range of new recessed and downlighting applications. The small size, yet remarkably powerful beam output and superior in-source color mixing, allows for a previously unobtainable freedom of design wherever high-flux density, directional light is required. LED Engin is committed to providing products that conserve natural resources and reduce greenhouse emissions; and reserves the right to make changes to improve performance without notice.

For more information, please contact LEDE-Sales@osram.com or +1 408 922-7200.

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